



MMDT3904VC

DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

Epitaxial Planar Die Construction

Ideal for Low Power Amplification and Switching

Ultra-Small Surface Mount Package

Lead Free By Design/RoHS Compliant (Note 4)

"Green Device" (Note 5)

Mechanical Data

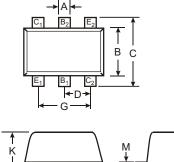
Case: SOT-563

Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

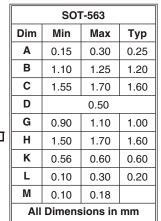
Moisture Sensitivity: Level 1 per J-STD-020C Terminals: Finish - Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208

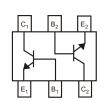
Terminal Connections: See Diagram

Marking (See Page 2): APK
Ordering Information: See Below
Date Code Information: See Page 2
Weight: 0.003 grams (approximate)



SEE NOTE 1





Maximum Ratings @ T_A = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current - Continuous	Ic	200	mA
Power Dissipation (Note 2)	P _d	200	mW
Thermal Resistance, Junction to Ambient	R JA	625	C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	С

Ordering Information (Note 3)

Device	Packaging	Shipping		
MMDT3904VC-7	SOT-563	3000/Tape & Reel		

Notes

- 1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180 rotated, or mixed (both ways).
- 2. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 3. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.
- 4. No purposefully added lead.
- 5. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

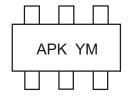


Electrical Characteristics @ T_A = 25 C unless otherwise specified

Characteristic	Symbol	Symbol Min		Unit	Test Condition		
OFF CHARACTERISTICS (Note 6)							
Collector-Base Breakdown Voltage	V _{(BR)CBO}	V _{(BR)CBO} 60		V	I _C = 10 A, I _E = 0		
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	40		V	I _C = 1.0mA, I _B = 0		
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5.0		V	I _E = 10 A, I _C = 0		
Collector Cutoff Current	I _{CEX}		50	nA	V _{CE} = 30V, V _{EB(OFF)} = 3.0V		
Base Cutoff Current	I _{BL}		50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$		
ON CHARACTERISTICS (Note 6)	,		•	•			
DC Current Gain	h _{FE}	40 70 100 60 30	300		I _C = 100μA, V _{CE} = 1.0V I _C = 1.0mA, V _{CE} = 1.0V I _C = 10mA, V _{CE} = 1.0V I _C = 50mA, V _{CE} = 1.0V I _C = 100mA, V _{CE} = 1.0V		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.20 0.30	V	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA		
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.65	0.85 0.95	V	I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA		
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance	C _{obo}		4.0	pF	$V_{CB} = 5.0V$, $f = 1.0MHz$, $I_E = 0$		
Input Capacitance	C _{ibo}		8.0	pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_C = 0$		
Input Impedance	h _{ie}	1.0	10	k			
Voltage Feedback Ratio	h _{re}	0.5	8.0	x 10 ⁻⁴	V _{CE} = 10V, I _C = 1.0mA,		
Small Signal Current Gain	h _{fe}	100	400		f = 1.0kHz		
Output Admittance	h _{oe}	1.0	40	S			
Current Gain-Bandwidth Product	f _T	300		MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz		
Noise Figure	NF		5.0	dB	V _{CE} = 5.0V, I _C = 100 A, R _S = 1.0k f = 1.0kHz		
SWITCHING CHARACTERISTICS	,		•	•	•		
Delay Time	t _d		35	ns	V _{CC} = 3.0V, I _C = 10mA,		
Rise Time	t _r		35	ns	$V_{BE(off)} = -0.5V, I_{B1} = 1.0mA$		
Storage Time	t _s		200	ns	V _{CC} = 3.0V, I _C = 10mA,		
Fall Time	t _f		50	ns	$I_{B1} = I_{B2} = 1.0 \text{mA}$		

Notes: 6. Short duration test pulse used to minimize self-heating.

Marking Information



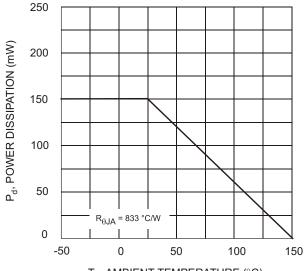
APK = Product Type Marking Code YM = Date Code Marking Y = Year ex: R = 2004 M = Month ex: 9 = September

Date Code Key

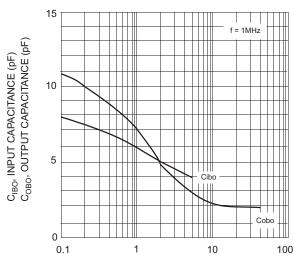
Year	2005	2006	2007	2008	2009	2010	2011	2012
Code	S	Т	U	V	W	X	Υ	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

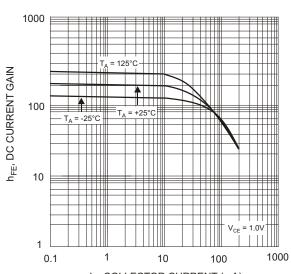




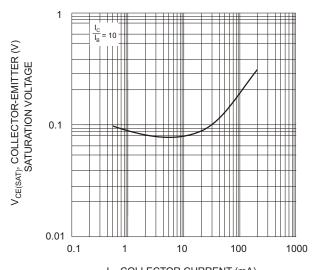
T_A, AMBIENT TEMPERATURE (°C) Fig. 1, Derating Curve - Total



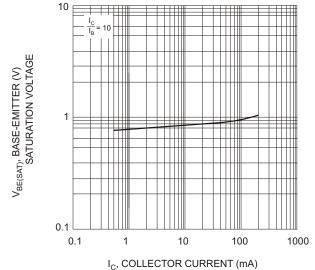
V_{CB}, COLLECTOR-BASE VOLTAGE (V) Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage



I_C, COLLECTOR CURRENT (mA) Fig. 3, Typical DC Current Gain vs Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current





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